#### **CJD41C NPN CJD42C PNP**

## SURFACE MOUNT SILICON **COMPLEMENTARY POWER TRANSISTORS**





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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CJD41C and CJD42C are complementary silicon power transistors manufactured by the epitaxial base process, mounted in a surface mount package, and designed for power amplifier and high speed switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T <sub>C</sub> =25°C unless other	erwise noted)
	SYME
Collector-Base Voltage	Vcp

111 Balling III 14 11 11 10 20 0 01 10 10 10 10 10 10 10 10 10 10 10	o notou,		
-	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	100	V
Collector-Emitter Voltage	$V_{CEO}$	100	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Continuous Collector Current	$I_{\mathbb{C}}$	6.0	Α
Peak Collector Current	I <sub>CM</sub>	10	Α
Continuous Base Current	Ι <sub>Β</sub>	2.0	Α
Power Dissipation	$P_{D}$	20	W
Power Dissipation (T <sub>A</sub> =25°C)	$P_{D}$	1.75	W
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance	$\Theta$ JC	6.25	°C/W
Thermal Resistance	ΘιΔ	71.4	°C/W

## **ELECTRICAL CHARACTERISTICS:** (T<sub>C</sub>=25°C unless otherwise noted)

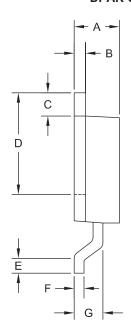
TEST CONDITIONS	MIN	MAX	UNITS
V <sub>CE</sub> =60V		50	μΑ
V <sub>CE</sub> =100V		10	μΑ
V <sub>EB</sub> =5.0V		500	μΑ
I <sub>C</sub> =30mA	100		V
I <sub>C</sub> =6.0A, I <sub>B</sub> =600mA		1.5	V
V <sub>CE</sub> =4.0V, I <sub>C</sub> =6.0A		2.0	V
V <sub>CE</sub> =4.0V, I <sub>C</sub> =300mA	30		
$V_{CE}$ =4.0V, $I_{C}$ =3.0A	15	75	
$V_{CE}$ =10V, $I_{C}$ =500mA, f=1.0MHz	3.0		MHz
$V_{CE}$ =10V, $I_{C}$ =500mA, f=1.0kHz	20		
	V <sub>CE</sub> =60V V <sub>CE</sub> =100V V <sub>EB</sub> =5.0V I <sub>C</sub> =30mA I <sub>C</sub> =6.0A, I <sub>B</sub> =600mA V <sub>CE</sub> =4.0V, I <sub>C</sub> =6.0A V <sub>CE</sub> =4.0V, I <sub>C</sub> =300mA V <sub>CE</sub> =4.0V, I <sub>C</sub> =3.0A V <sub>CE</sub> =10V, I <sub>C</sub> =500mA, f=1.0MHz	V <sub>CE</sub> =60V V <sub>CE</sub> =100V V <sub>EB</sub> =5.0V I <sub>C</sub> =30mA 100 I <sub>C</sub> =6.0A, I <sub>B</sub> =600mA V <sub>CE</sub> =4.0V, I <sub>C</sub> =6.0A V <sub>CE</sub> =4.0V, I <sub>C</sub> =300mA 30 V <sub>CE</sub> =4.0V, I <sub>C</sub> =300mA 15 V <sub>CE</sub> =10V, I <sub>C</sub> =500mA, f=1.0MHz 3.0	VCE=60V 50   VCE=100V 10   VEB=5.0V 500   I <sub>C</sub> =30mA 100   I <sub>C</sub> =6.0A, I <sub>B</sub> =600mA 1.5   V <sub>CE</sub> =4.0V, I <sub>C</sub> =6.0A 2.0   V <sub>CE</sub> =4.0V, I <sub>C</sub> =300mA 30   V <sub>CE</sub> =4.0V, I <sub>C</sub> =3.0A 15 75   V <sub>CE</sub> =10V, I <sub>C</sub> =500mA, f=1.0MHz 3.0

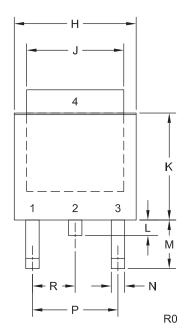
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## **DPAK CASE - MECHANICAL OUTLINE**





# LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- 4) Collector

#### MARKING: FULL PART NUMBER

	DIM	ENSION:				
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0.083	0.108	2.10	2.75		
В	0.016	0.032	0.40	0.81		
С	0.035	0.063	0.89	1.60		
D	0.203	0.228	5.15	5.79		
E	0.020	-	0.51	-		
F	0.018	0.024	0.45	0.60		
G	0.051	0.071	1.30	1.80		
Н	0.248	0.268	6.30	6.81		
J	0.197	0.217	5.00	5.50		
K	0.209	0.245	5.30	6.22		
L	0.025	0.040	0.64	1.02		
M	0.090	0.115	2.30	2.91		
N	0.012	0.045	0.30	1.14		
Р	0.180		4.60			
R	0.090		2.30			
DDAK (DEV) DO						

DPAK (REV: R0)

R3 (21-January 2013)

#### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

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